

74LVC1G123

Single retriggerable monostable multivibrator; Schmitt trigger inputs

Rev. 1 — 23 January 2012

Product data sheet

1. General description

The 74LVC1G123 is a single retriggerable monostable multivibrator with Schmitt trigger inputs. Output pulse width is controlled by three methods:

1. The basic pulse is programmed by selection of an external resistor (R_{EXT}) and capacitor (C_{EXT}).
2. Once triggered, the basic output pulse width may be extended by retriggering the gated active LOW-going edge input (\overline{A}) or the active HIGH-going edge input (B). By repeating this process, the output pulse period ($Q = \text{HIGH}$) can be made as long as desired. Alternatively an output delay can be terminated at any time by a LOW-going edge on input \overline{CLR} , which also inhibits the triggering.
3. An internal connection from \overline{CLR} to the input gates makes it possible to trigger the circuit by a HIGH-going signal at input \overline{CLR} .

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of these devices as translators in a mixed 3.3 V and 5 V environment. Schmitt-trigger inputs, makes the circuit highly tolerant to slower input rise and fall times.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.65 V to 5.5 V
- High noise immunity
- ± 24 mA output drive ($V_{CC} = 3.0$ V)
- CMOS low power consumption
- DC triggered from active HIGH or active LOW inputs
- Retriggerable for very long pulses up to 100 % duty factor
- Direct reset terminates output pulse
- Schmitt trigger on all inputs
- Complies with JEDEC standard:
 - ◆ JESD8-7 (1.65 V to 1.95 V)
 - ◆ JESD8-5 (2.3 V to 2.7 V)
 - ◆ JESD8-B/JESD36 (2.7 V to 3.6 V)
- Power-on-reset on outputs
- Latch-up performance exceeds 100 mA
- Direct interface with TTL levels



- Inputs accept voltages up to 5.5 V
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Multiple package options
- Specified from $-40\text{ }^{\circ}\text{C}$ to $+85\text{ }^{\circ}\text{C}$ and $-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G123DP	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	TSSOP8	plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm	SOT505-2
74LVC1G123DC	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74LVC1G123GT	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body $1 \times 1.95 \times 0.5\text{ mm}$	SOT833-1
74LVC1G123GF	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.35 \times 1 \times 0.5\text{ mm}$	SOT1089
74LVC1G123GD	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	XSON8U	plastic extremely thin small outline package; no leads; 8 terminals; UTLP based; body $3 \times 2 \times 0.5\text{ mm}$	SOT996-2
74LVC1G123GM	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	XQFN8	plastic extremely thin quad flat package; no leads; 8 terminals; body $1.6 \times 1.6 \times 0.5\text{ mm}$	SOT902-2
74LVC1G123GN	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.2 \times 1.0 \times 0.35\text{ mm}$	SOT1116
74LVC1G123GS	$-40\text{ }^{\circ}\text{C}$ to $+125\text{ }^{\circ}\text{C}$	XSON8	extremely thin small outline package; no leads; 8 terminals; body $1.35 \times 1.0 \times 0.35\text{ mm}$	SOT1203

4. Marking

Table 2. Marking codes

Type number	Marking code ^[1]
74LVC1G123DP	Y3
74LVC1G123DC	Y3
74LVC1G123GT	Y3
74LVC1G123GF	Y3
74LVC1G123GD	Y3
74LVC1G123GM	Y3
74LVC1G123GN	Y3
74LVC1G123GS	Y3

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram

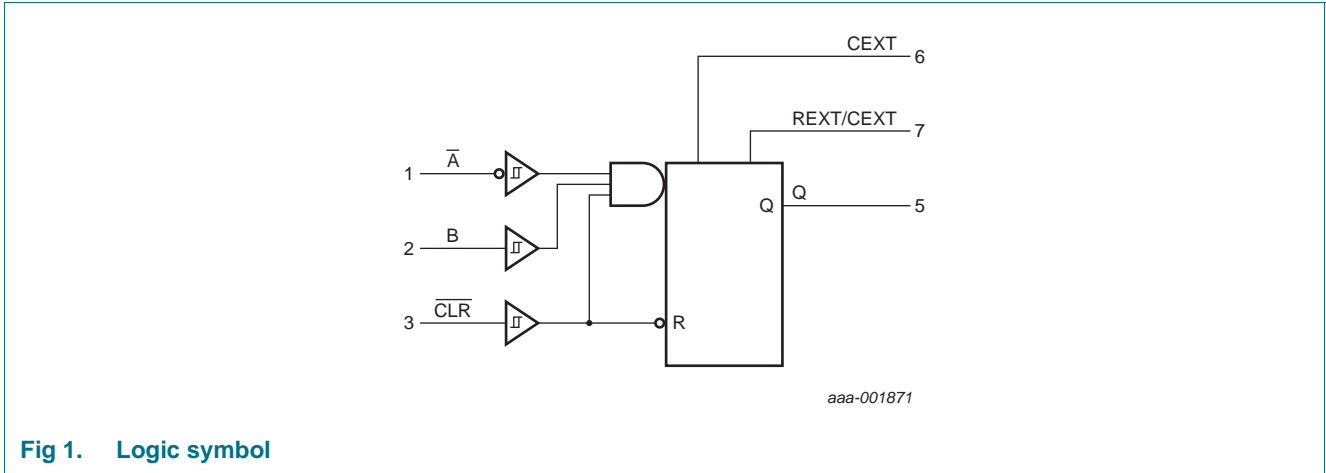


Fig 1. Logic symbol

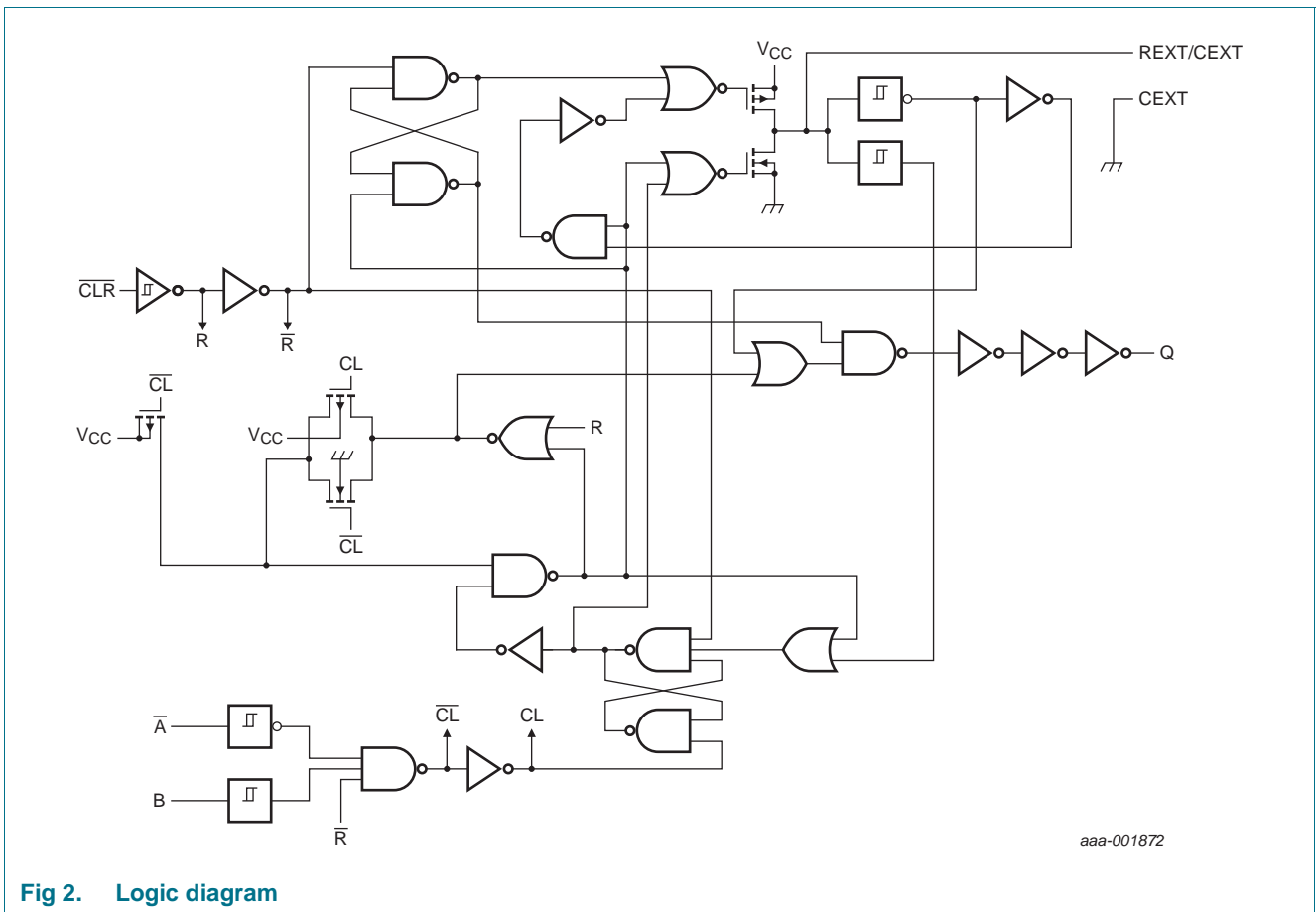
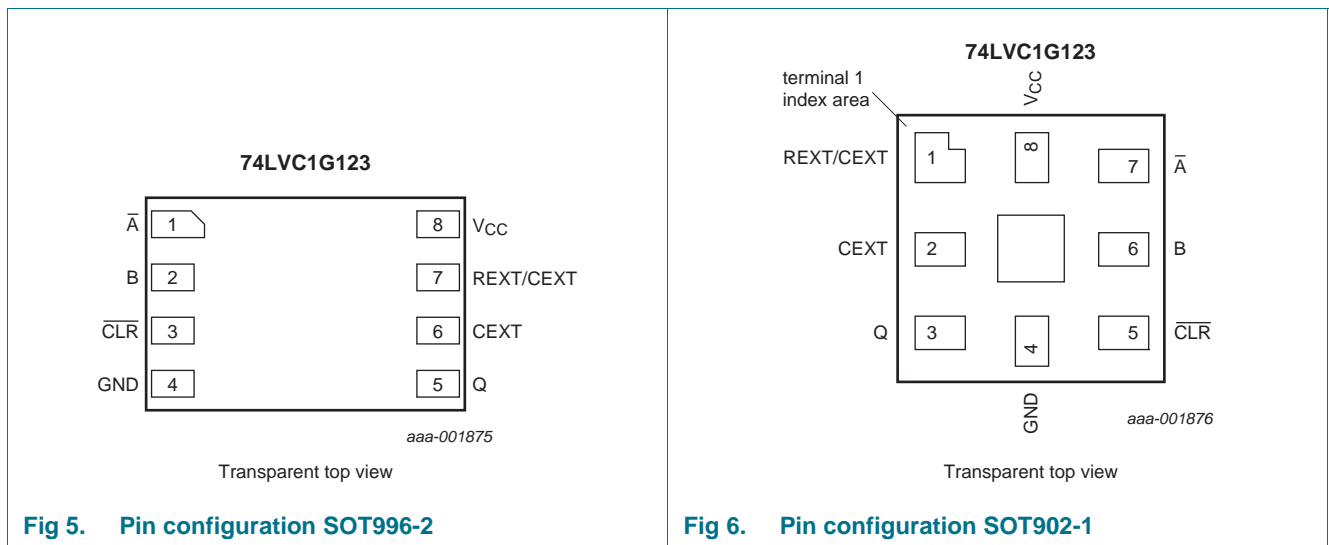
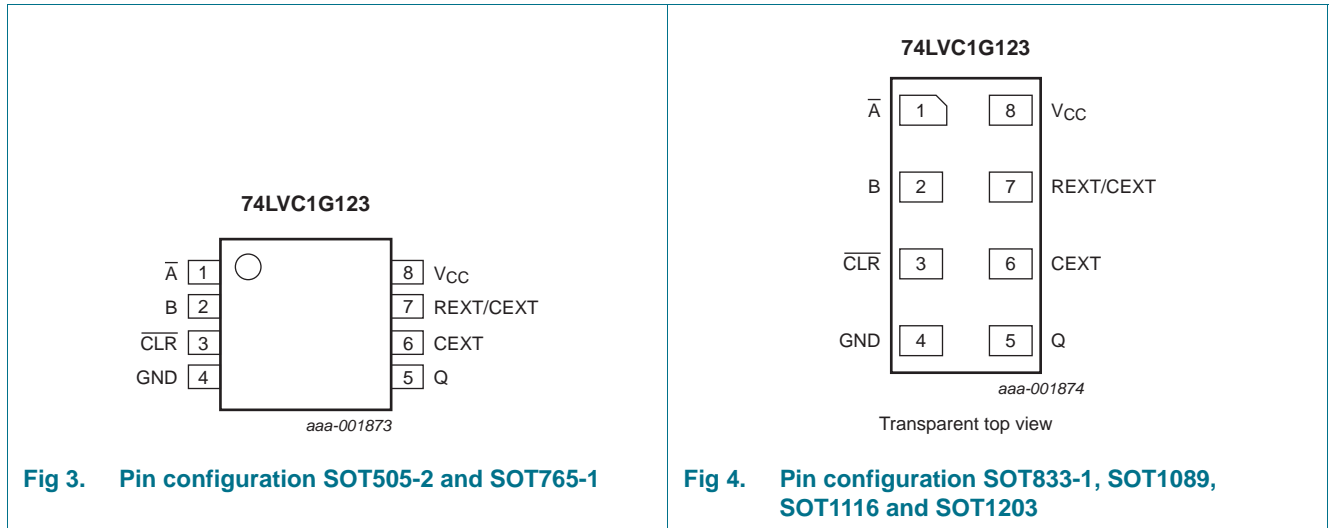


Fig 2. Logic diagram

6. Pinning information

6.1 Pinning






6.2 Pin description

Table 3. Pin description



Symbol	Pin		Description
	SOT505-2, SOT765-1, SOT833-1, SOT1089, SOT996-2, SOT1116 and SOT1203	SOT902-2	
\overline{A}	1	7	negative-edge triggered input
B	2	6	positive-edge triggered input
\overline{CLR}	3	5	direct reset LOW and positive-edge triggered input
GND	4	4	ground (0 V)
Q	5	3	active HIGH output
CEXT	6	2	external capacitor connection
REXT/CEXT	7	1	external resistor and capacitor connection
V _{CC}	8	8	supply voltage

7. Functional description

Table 4. Function table^[1]

Input			Output
CLR	\overline{A}	B	Q
L	X	X	L
X	H	X	L ^[2]
X	X	L	L ^[2]
H	L	↑	
H	↓	H	
↑	L	H	

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; ↑ = LOW-to-HIGH transition; ↓ = HIGH-to-LOW transition;

 = one HIGH level output pulse;  = one LOW level output pulse.

[2] If the monostable was triggered before this condition was established, the pulse will continue as programmed.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+6.5	V
V_I	input voltage		[1] -0.5	+6.5	V
V_O	output voltage	Active mode	[1] -0.5	$V_{CC} + 0.5$	V
		Power-down mode	[1][2] -0.5	+6.5	V
I_{IK}	input clamping current	$V_I < 0$ V	-50	-	mA
I_{OK}	output clamping current	$V_O < 0$ V or $V_O > V_{CC}$	-	± 50	mA
I_O	output current	$V_O = 0$ V to V_{CC}	-	± 50	mA
I_{CC}	supply current		-	100	mA
I_{GND}	ground current		-100	-	mA
T_{stg}	storage temperature		-65	+150	°C
P_{tot}	total power dissipation	$T_{amb} = -40$ °C to +125 °C	[3] -	300	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When $V_{CC} = 0$ V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP8 package: above 55 °C the value of P_{tot} derates linearly with 2.5 mW/K.

For VSSOP8 package: above 110 °C the value of P_{tot} derates linearly with 8 mW/K.

For XSON8, XSON8U and XQFN8 packages: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.65	5.5	V
V_I	input voltage		0	5.5	V
V_O	output voltage	Active mode	0	V_{CC}	V
		Power-down mode	0	5.5	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.65$ V to 5.5 V	-	1	ms/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$T_{amb} = -40\text{ °C to }+85\text{ °C}$ [1]						
V_{OH}	HIGH-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = -100\text{ }\mu\text{A}$; $V_{CC} = 1.65\text{ V to }5.5\text{ V}$	$V_{CC} - 0.1$	-	-	V
		$I_O = -4\text{ mA}$; $V_{CC} = 1.65\text{ V}$	1.2	-	-	V
		$I_O = -8\text{ mA}$; $V_{CC} = 2.3\text{ V}$	1.9	-	-	V
		$I_O = -12\text{ mA}$; $V_{CC} = 2.7\text{ V}$	2.2	-	-	V
		$I_O = -24\text{ mA}$; $V_{CC} = 3.0\text{ V}$	2.4	-	-	V
		$I_O = -32\text{ mA}$; $V_{CC} = 4.5\text{ V}$	3.8	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{T+}$ or V_{T-}				
		$I_O = 100\text{ }\mu\text{A}$; $V_{CC} = 1.65\text{ V to }5.5\text{ V}$	-	-	0.1	V
		$I_O = 4\text{ mA}$; $V_{CC} = 1.65\text{ V}$	-	-	0.45	V
		$I_O = 8\text{ mA}$; $V_{CC} = 2.3\text{ V}$	-	-	0.3	V
		$I_O = 12\text{ mA}$; $V_{CC} = 2.7\text{ V}$	-	-	0.4	V
		$I_O = 24\text{ mA}$; $V_{CC} = 3.0\text{ V}$	-	-	0.55	V
		$I_O = 32\text{ mA}$; $V_{CC} = 4.5\text{ V}$	-	-	0.55	V
I_I	input leakage current	$V_I = 5.5\text{ V or GND}$; $V_{CC} = 0\text{ V to }5.5\text{ V}$	-	-	± 2	μA
I_{OFF}	power-off leakage current	V_I or $V_O = 5.5\text{ V}$; $V_{CC} = 0\text{ V}$	-	-	± 2	μA
I_{CC}	supply current	$V_I = 5.5\text{ V or GND}$;				
		Quiescent; $V_{CC} = 1.65\text{ V to }5.5\text{ V}$; $I_O = 0\text{ A}$	-	0.1	10	μA
		Active state; $R_{EXT}/C_{EXT} = 0.5V_{CC}$				
		$V_{CC} = 1.65\text{ V}$	-	-	80	μA
		$V_{CC} = 2.3\text{ V}$	-	-	130	μA
		$V_{CC} = 3\text{ V}$	-	-	240	μA
		$V_{CC} = 4.5\text{ V}$	-	-	400	μA
$V_{CC} = 5.5\text{ V}$	-	-	650	μA		
C_I	input capacitance		-	2.0	-	pF

Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = -40 °C to +125 °C						
V _{OH}	HIGH-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = -100 μA; V _{CC} = 1.65 V to 5.5 V	V _{CC} - 0.1	-	-	V
		I _O = -4 mA; V _{CC} = 1.65 V	1.2	-	-	V
		I _O = -8 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -12 mA; V _{CC} = 2.7 V	2.2	-	-	V
		I _O = -24 mA; V _{CC} = 3.0 V	2.4	-	-	V
		I _O = -32 mA; V _{CC} = 4.5 V	3.8	-	-	V
V _{OL}	LOW-level output voltage	V _I = V _{T+} or V _{T-}				
		I _O = 100 μA; V _{CC} = 1.65 V to 5.5 V	-	-	0.1	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	V
		I _O = 8 mA; V _{CC} = 2.3 V	-	-	0.3	V
		I _O = 12 mA; V _{CC} = 2.7 V	-	-	0.4	V
		I _O = 24 mA; V _{CC} = 3.0 V	-	-	0.55	V
		I _O = 32 mA; V _{CC} = 4.5 V	-	-	0.55	V
I _I	input leakage current	V _I = 5.5 V or GND; V _{CC} = 0 V to 5.5 V	-	-	±10	μA
I _{OFF}	power-off leakage current	V _I or V _O = 5.5 V; V _{CC} = 0 V	-	-	±10	μA
I _{CC}	supply current	V _I = 5.5 V or GND;				
		Quiescent; V _{CC} = 1.65 V to 5.5 V; I _O = 0 A	-	-	20	μA
		Active state; R _{EXT} /C _{EXT} = 0.5V _{CC}				
		V _{CC} = 1.65 V	-	-	80	μA
		V _{CC} = 2.3 V	-	-	130	μA
		V _{CC} = 3 V	-	-	240	μA
		V _{CC} = 4.5 V	-	-	400	μA
		V _{CC} = 5.5 V	-	-	650	μA

[1] All typical values are measured at T_{amb} = 25 °C.

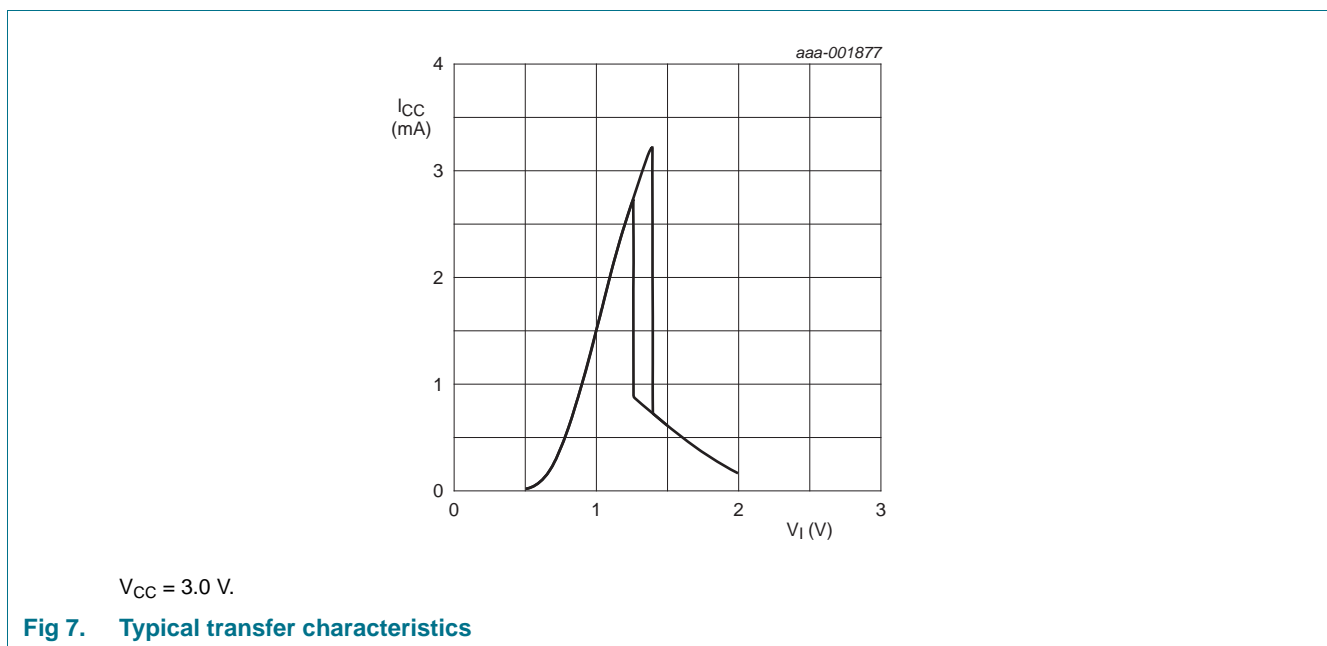
Table 8. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 19](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
V _{T+}	positive-going threshold voltage	\overline{A} , B and \overline{CLR} input; see Figure 7						
		V _{CC} = 1.65 V to 1.95 V	0.72	0.98	1.22	0.71	1.22	V
		V _{CC} = 2.3 V to 2.7 V	0.97	1.26	1.52	0.97	1.52	V
		V _{CC} = 3.0 V to 3.6 V	1.20	1.58	1.90	1.20	1.90	V
V _{T-}	negative-going threshold voltage	\overline{A} , B and \overline{CLR} input; see Figure 7						
		V _{CC} = 1.65 V to 1.95 V	0.56	0.81	1.04	0.56	1.04	V
		V _{CC} = 2.3 V to 2.7 V	0.83	1.09	1.33	0.82	1.33	V
		V _{CC} = 3.0 V to 3.6 V	1.08	1.40	1.70	1.08	1.72	V
V _H	hysteresis voltage	\overline{A} , B and \overline{CLR} input; (V _{T+} - V _{T-}); see Figure 7						
		V _{CC} = 1.8 V	61	170	295	54	295	mV
		V _{CC} = 2.3 V	41	174	304	41	304	mV
		V _{CC} = 3.0 V	40	183	319	40	319	mV
		V _{CC} = 4.5 V	32	199	363	26	363	mV
		V _{CC} = 5.5 V	61	170	295	0.71	1.22	mV

[1] All typical values are measured at T_{amb} = 25 °C

10.1 Waveform transfer characteristics



11. Dynamic characteristics

Table 9. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 19](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t _{pd}	propagation delay	A, B to Q; see Figure 8 ^[2]						
		C _L = 15pF;						
		V _{CC} = 1.65 V to 1.95 V	2.5	7.1	16.3	2.5	17.6	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	-	10.3	1.9	11.2	ns
		V _{CC} = 2.7 V	1.9	-	8.5	1.9	9.3	ns
		V _{CC} = 3.0 V to 3.6 V	1.5	-	7.6	1.5	8.3	ns
		V _{CC} = 4.5 V to 5.5 V	1.2	-	5.3	1.2	5.8	ns
		C _L = 30 pF or C _L = 50 pF						
		V _{CC} = 1.65 V to 1.95 V	2.9	7.8	17.6	2.9	19.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.2	-	11.3	2.2	12.3	ns
		V _{CC} = 2.7 V	2.7	-	10.5	2.7	11.4	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	-	9.5	2.0	10.3	ns
		V _{CC} = 4.5 V to 5.5 V	1.5	-	6.7	1.5	7.2	ns
		CLR to Q; see Figure 8						
		C _L = 15pF;						
		V _{CC} = 1.65 V to 1.95 V	3.0	6.9	16.2	3.0	17.4	ns
		V _{CC} = 2.3 V to 2.7 V	2.2	-	9.6	2.2	10.5	ns
		V _{CC} = 2.7 V	2.2	-	8.2	2.2	8.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	-	7.3	2.0	8.0	ns
		V _{CC} = 4.5 V to 5.5 V	1.5	-	5.1	1.5	5.5	ns
		C _L = 30 pF or C _L = 50 pF						
		V _{CC} = 1.65 V to 1.95 V	3.3	7.5	17.2	3.8	18.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	-	10.3	2.0	11.2	ns
		V _{CC} = 2.7 V	2.8	-	9.3	2.8	10.2	ns
V _{CC} = 3.0 V to 3.6 V	1.5	-	8.4	1.5	9.2	ns		
V _{CC} = 4.5 V to 5.5 V	1.5	-	6.0	1.5	6.6	ns		

Single retriggerable monostable multivibrator; Schmitt trigger inputs

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 19](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t _{pd}	propagation delay	CLR to Q (trigger); see Figure 8						
		C _L = 15pF;						
		V _{CC} = 1.65 V to 1.95 V	2.7	7.6	17.4	2.7	18.9	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	-	11.0	2.1	12.0	ns
		V _{CC} = 2.7 V	2.1	-	9.2	2.1	10.0	ns
		V _{CC} = 3.0 V to 3.6 V	1.7	-	8.2	1.7	8.9	ns
		V _{CC} = 4.5 V to 5.5 V	1.4	-	5.9	1.4	6.4	ns
		C _L = 30 pF or C _L = 50 pF						
		V _{CC} = 1.65 V to 1.95 V	3.1	8.3	18.8	3.3	20.3	ns
		V _{CC} = 2.3 V to 2.7 V	2.5	-	12.0	2.5	13.1	ns
		V _{CC} = 2.7 V	2.8	-	11.1	2.8	12.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	-	10.1	2.0	11.0	ns
		V _{CC} = 4.5 V to 5.5 V	1.5	-	7.1	1.5	7.7	ns
		t _w	pulse width	input \overline{A} LOW; B HIGH; see Figure 8 and 9				
V _{CC} = 1.65 V to 1.95 V	8.0			-	-	8.0	-	ns
V _{CC} = 2.3 V to 2.7 V	4.0			-	-	4.0	-	ns
V _{CC} = 2.7 V	3.0			-	-	3.0	-	ns
V _{CC} = 3.0 V to 3.6 V	3.0			-	-	3.0	-	ns
V _{CC} = 4.5 V to 5.5 V	2.5			-	-	2.5	-	ns
input \overline{CLR} LOW; see Figure 8 and 10								
V _{CC} = 1.65 V to 1.95 V	8.0			-	-	8.0	-	ns
V _{CC} = 2.3 V to 2.7 V	4.0			-	-	4.0	-	ns
V _{CC} = 2.7 V	3.0			-	-	3.0	-	ns
V _{CC} = 3.0 V to 3.6 V	3.0			-	-	3.0	-	ns
V _{CC} = 4.5 V to 5.5 V	2.5			-	-	2.5	-	ns

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 19](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
t _w	pulse width	output Q HIGH; see Figure 8 , 9 and 10 ; ^[3] R _{EXT} = 10 kΩ						
		C _{EXT} = 100 pF						
		V _{CC} = 1.65 V to 1.95 V	-	1.4	2.2	-	2.2	μs
		V _{CC} = 2.3 V to 2.7 V	-	1.3	1.8	-	1.8	μs
		V _{CC} = 2.7 V	-	1.2	1.8	-	1.8	μs
		V _{CC} = 3.0 V to 3.6 V	-	1.2	1.8	-	1.8	μs
		V _{CC} = 4.5 V to 5.5 V	-	1.2	1.8	-	1.8	μs
		C _{EXT} = 0.01 μF ^[3]						
		V _{CC} = 1.65 V to 1.95 V	-	100	110	-	110	μs
		V _{CC} = 2.3 V to 2.7 V	-	100	110	-	110	μs
		V _{CC} = 2.7 V	-	100	110	-	110	μs
		V _{CC} = 3.0 V to 3.6 V	-	100	110	-	110	μs
		V _{CC} = 4.5 V to 5.5 V	-	100	110	-	110	μs
		C _{EXT} = 0.1 μF ^[3]						
		V _{CC} = 1.65 V to 1.95 V	-	1.0	1.05	-	1.05	ms
		V _{CC} = 2.7 V	-	1.0	1.05	-	1.05	ms
		V _{CC} = 3.0 V to 3.6 V	-	1.0	1.05	-	1.05	ms
		V _{CC} = 3.0 V to 3.6 V	-	1.0	1.05	-	1.05	ms
		V _{CC} = 4.5 V to 5.5 V	-	1.0	1.05	-	1.05	ms
		t _{trig}	retrigger time	A, B; see Figure 9				
C _{EXT} = 100 pF; R _{EXT} = 5 kΩ								
V _{CC} = 1.65 V to 1.95 V	-			174	-	-	-	ns
V _{CC} = 2.3 V to 2.7 V	-			59	-	-	-	ns
C _{EXT} = 100 pF; R _{EXT} = 1 kΩ								
V _{CC} = 3.0 V to 3.6 V	-			32	-	-	-	ns
V _{CC} = 4.5 V to 5.5 V	-			20	-	-	-	ns
C _{EXT} = 100 μF; R _{EXT} = 5 kΩ								
V _{CC} = 1.65 V to 1.95 V	-			14	-	-	-	ms
V _{CC} = 2.3 V to 2.7 V	-			10	-	-	-	ms
C _{EXT} = 100 μF; R _{EXT} = 1 kΩ								
V _{CC} = 3.0 V to 3.6 V	-			10	-	-	-	ms
V _{CC} = 4.5 V to 5.5 V	-			8	-	-	-	ms
R _{EXT}	external timing resistor			see Figure 13 , 14 and 15				
		V _{CC} = 2.0 V	5	-	-	-	-	kΩ
		V _{CC} ≥ 3.0 V	1	-	-	-	-	kΩ
C _{EXT}	external timing capacitor	V _{CC} = 5.0 V; see Figure 13 , 14 and 15	-	-	-	-	-	pF

Table 9. Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see [Figure 19](#).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ ^[1]	Max	Min	Max	
C _{PD}	power dissipation capacitance	V _I = GND to V _{CC} ; C _{EXT} = 0 pF;						
		R _{EXT} = 5 kΩ						
		V _{CC} = 1.8 V	-	35	-	-	-	pF
		V _{CC} = 2.5 V	-	35	-	-	-	pF
		R _{EXT} = 1 kΩ						
		V _{CC} = 3.3 V	-	27	-	-	-	pF
		V _{CC} = 5.0 V	-	29	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PHL} and t_{PLH}; t_i is the same as t_{THL} and t_{TLH}

[3] For other R_{EXT} and C_{EXT} combinations see [Figure 13](#), [14](#) and [15](#). If C_{EXT} > 10 nF, the next formula is valid.

t_W = K × R_{EXT} × C_{EXT}, where:

t_W = typical output pulse width in ns;

R_{EXT} = external resistor in kΩ;

C_{EXT} = external capacitor in pF;

K = constant = 1; see [Figure 16](#) for typical "K" factor as function of V_{CC}.

12. Waveforms, graphs and test circuit

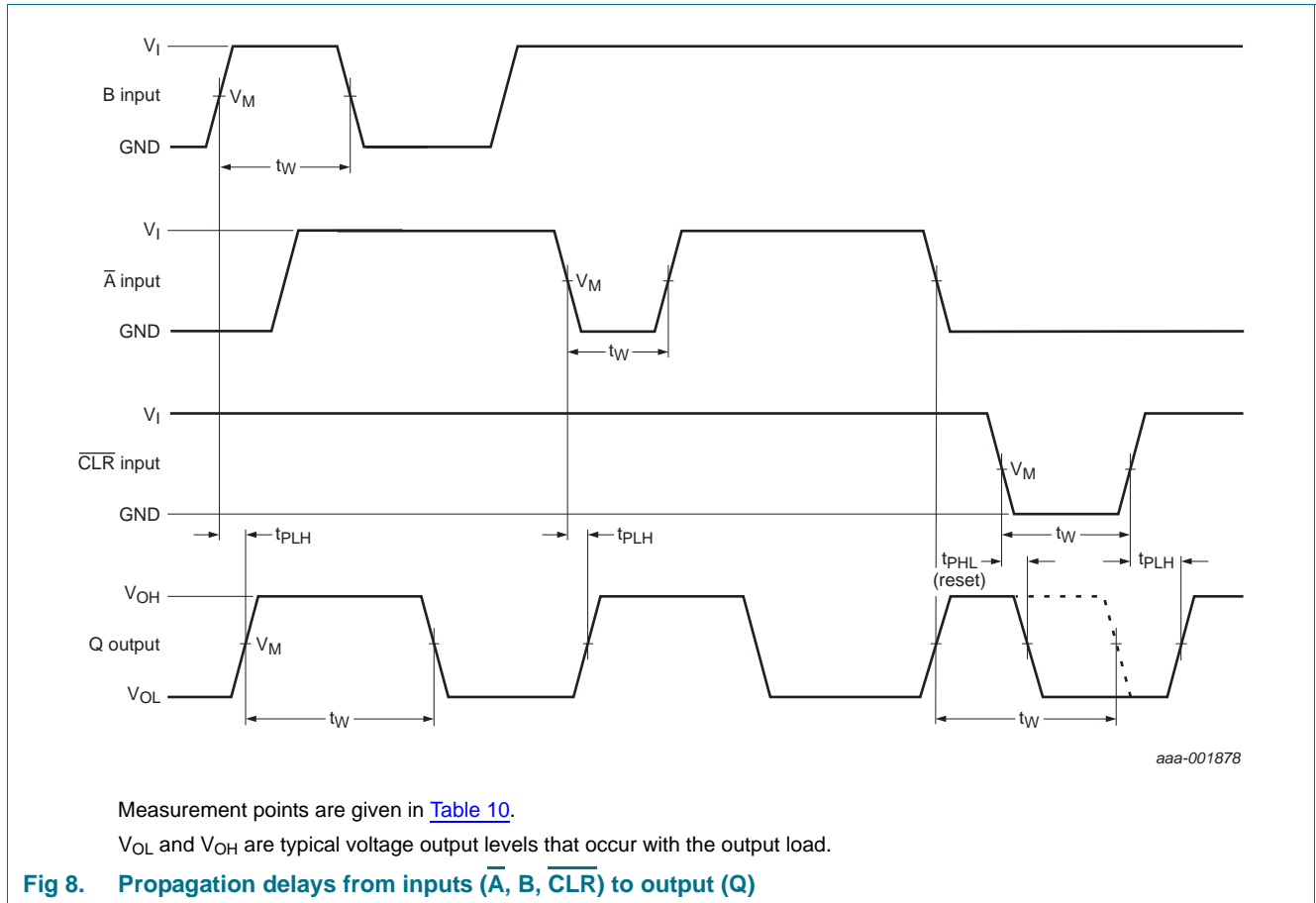
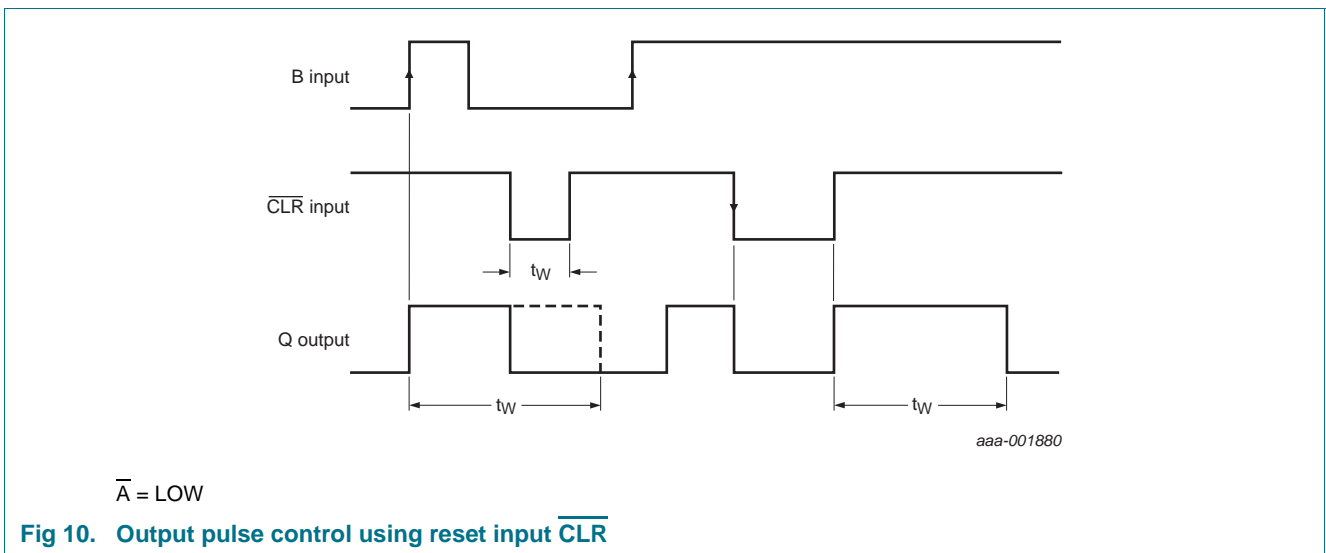
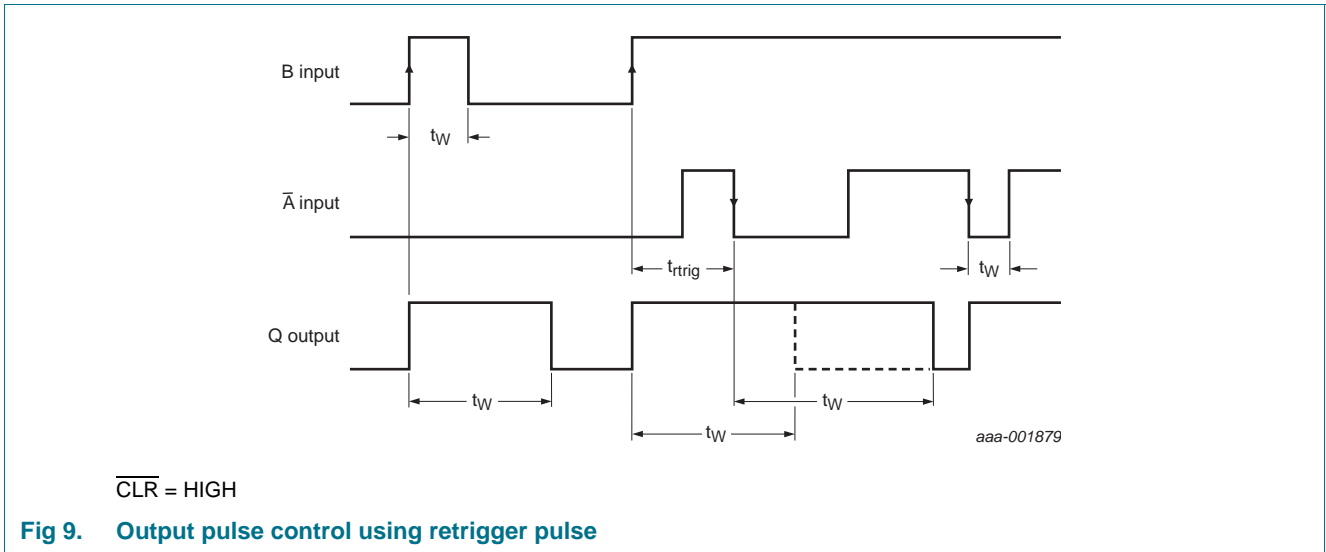


Table 10. Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65 V to 1.95 V	$0.5V_{CC}$	$0.5V_{CC}$
2.3 V to 2.7 V	$0.5V_{CC}$	$0.5V_{CC}$
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	$0.5V_{CC}$	$0.5V_{CC}$



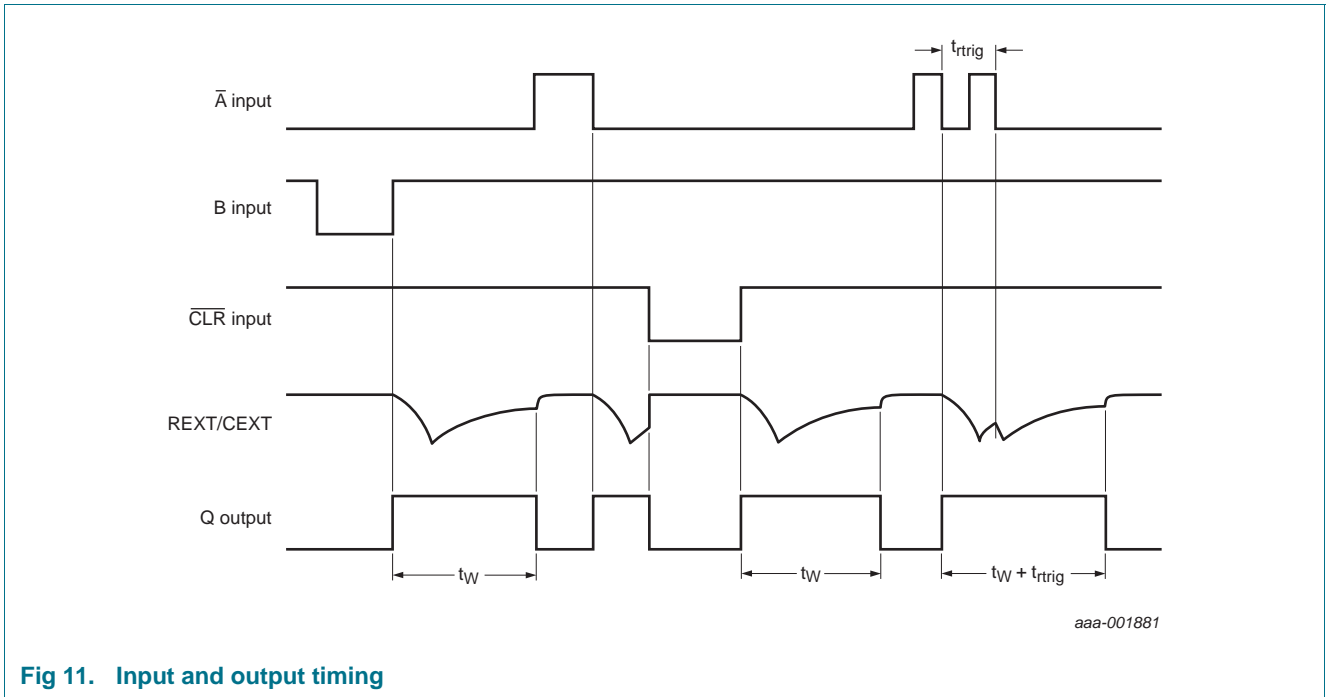


Fig 11. Input and output timing

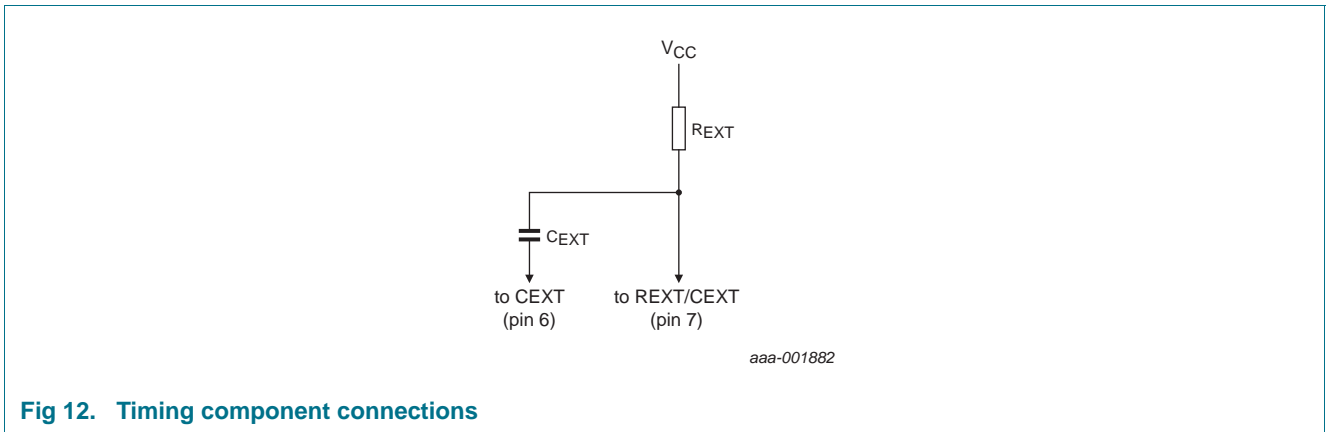
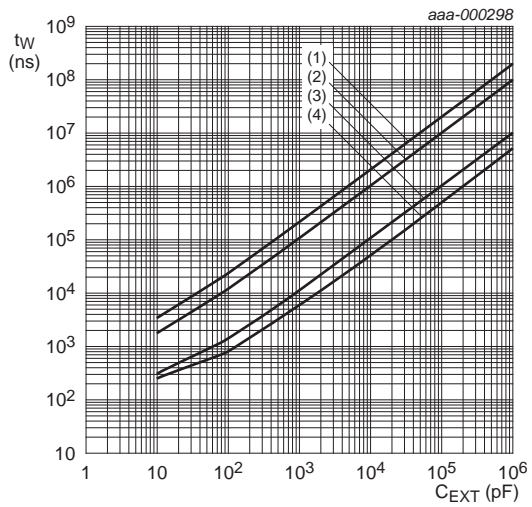
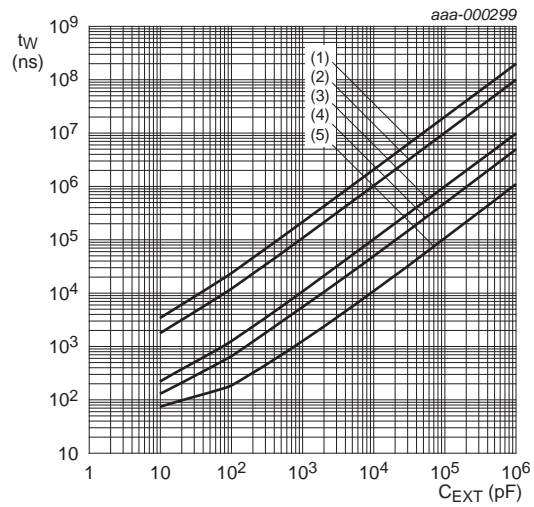


Fig 12. Timing component connections



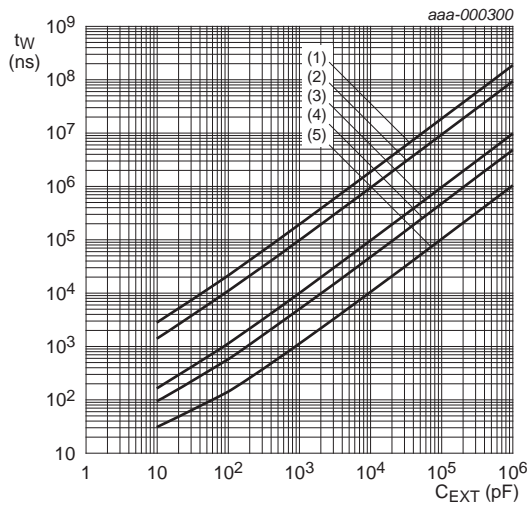
- $V_{CC} = 1.8\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (1) $R_{EXT} = 200\text{ k}\Omega$
 - (2) $R_{EXT} = 100\text{ k}\Omega$
 - (3) $R_{EXT} = 10\text{ k}\Omega$
 - (4) $R_{EXT} = 5\text{ k}\Omega$

Fig 13. Typical output pulse width as a function of the external capacitor value



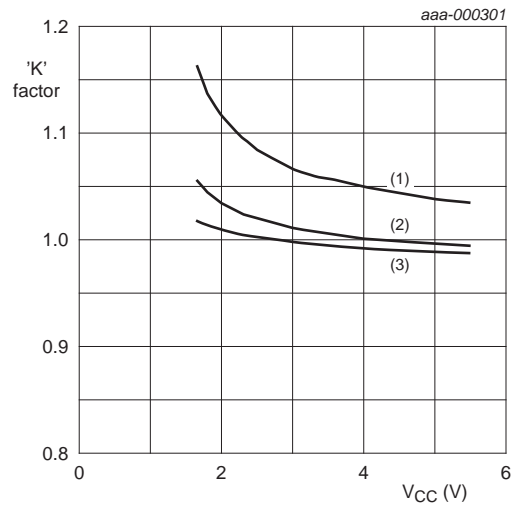
- $V_{CC} = 3.3\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (1) $R_{EXT} = 200\text{ k}\Omega$
 - (2) $R_{EXT} = 100\text{ k}\Omega$
 - (3) $R_{EXT} = 10\text{ k}\Omega$
 - (4) $R_{EXT} = 5\text{ k}\Omega$
 - (5) $R_{EXT} = 1\text{ k}\Omega$

Fig 14. Typical output pulse width as a function of the external capacitor value



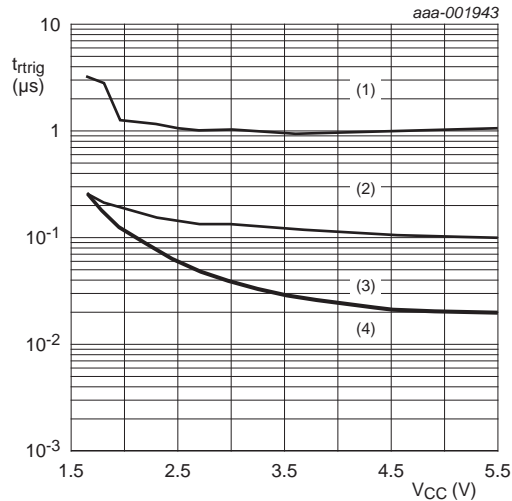
- $V_{CC} = 5.0\text{ V}; T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (1) $R_{EXT} = 200\text{ k}\Omega$
 - (2) $R_{EXT} = 100\text{ k}\Omega$
 - (3) $R_{EXT} = 10\text{ k}\Omega$
 - (4) $R_{EXT} = 5\text{ k}\Omega$
 - (5) $R_{EXT} = 1\text{ k}\Omega$

Fig 15. Typical output pulse width as a function of the external capacitor value



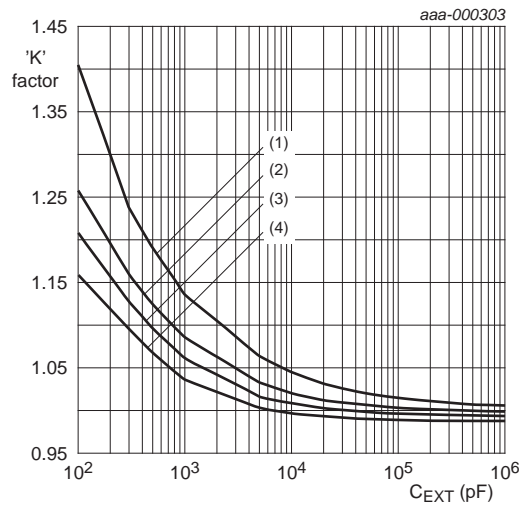
- $R_{EXT} = 10\text{ k}\Omega; T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (1) $C_{EXT} = 1000\text{ pF}$
 - (2) $C_{EXT} = 0.01\text{ }\mu\text{F}$
 - (3) $C_{EXT} = 0.1\text{ }\mu\text{F}$

Fig 16. Typical 'K' factor as function of V_{CC}



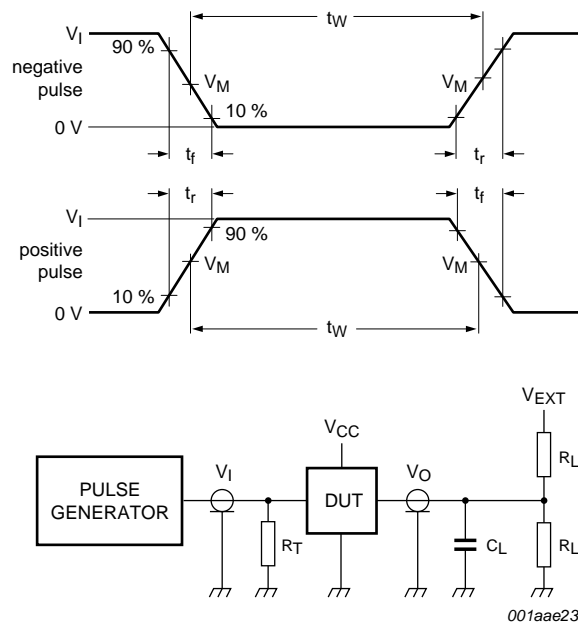
- $T_{amb} = 25\text{ }^{\circ}\text{C}.$
- (1) $C_{EXT} = 0.01\text{ }\mu\text{F}$
 - (2) $C_{EXT} = 1000\text{ pF}$
 - (3) $C_{EXT} = 100\text{ pF}$
 - (4) $C_{EXT} = 10\text{ pF}$

Fig 17. Minimum retrigger time as function of the supply voltage



- $R_{EXT} = 10\text{ k}\Omega; T_{amb} = 25\text{ }^\circ\text{C}.$
- (1) $V_{CC} = 1.8\text{ V}$
 - (2) $V_{CC} = 2.5\text{ V}$
 - (3) $V_{CC} = 3.3\text{ V}$
 - (4) $V_{CC} = 5.0\text{ V}$

Fig 18. Typical 'K' factor as function of C_{EXT}



Test data is given in [Table 11](#).

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

V_{EXT} = Test voltage for switching times.

Fig 19. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Input	Load	V_{EXT}		
V_{CC}	V_I	C_L	t_{PLH}, t_{PHL}		
	t_r, t_f	R_L			
1.65 V to 1.95 V	V_{CC}	≤ 2.0 ns	15 pF	1 M Ω	open
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	15 pF	1 M Ω	open
2.7 V	2.7 V	≤ 2.5 ns	15 pF	1 M Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	15 pF	1 M Ω	open
4.5 V to 5.5 V	V_{CC}	≤ 2.5 ns	15 pF	1 M Ω	open
1.65 V to 1.95 V	V_{CC}	≤ 2.0 ns	30 pF	1 k Ω	open
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V_{CC}	≤ 2.5 ns	50 pF	500 Ω	open

13. Package outline

TSSOP8: plastic thin shrink small outline package; 8 leads; body width 3 mm; lead length 0.5 mm SOT505-2

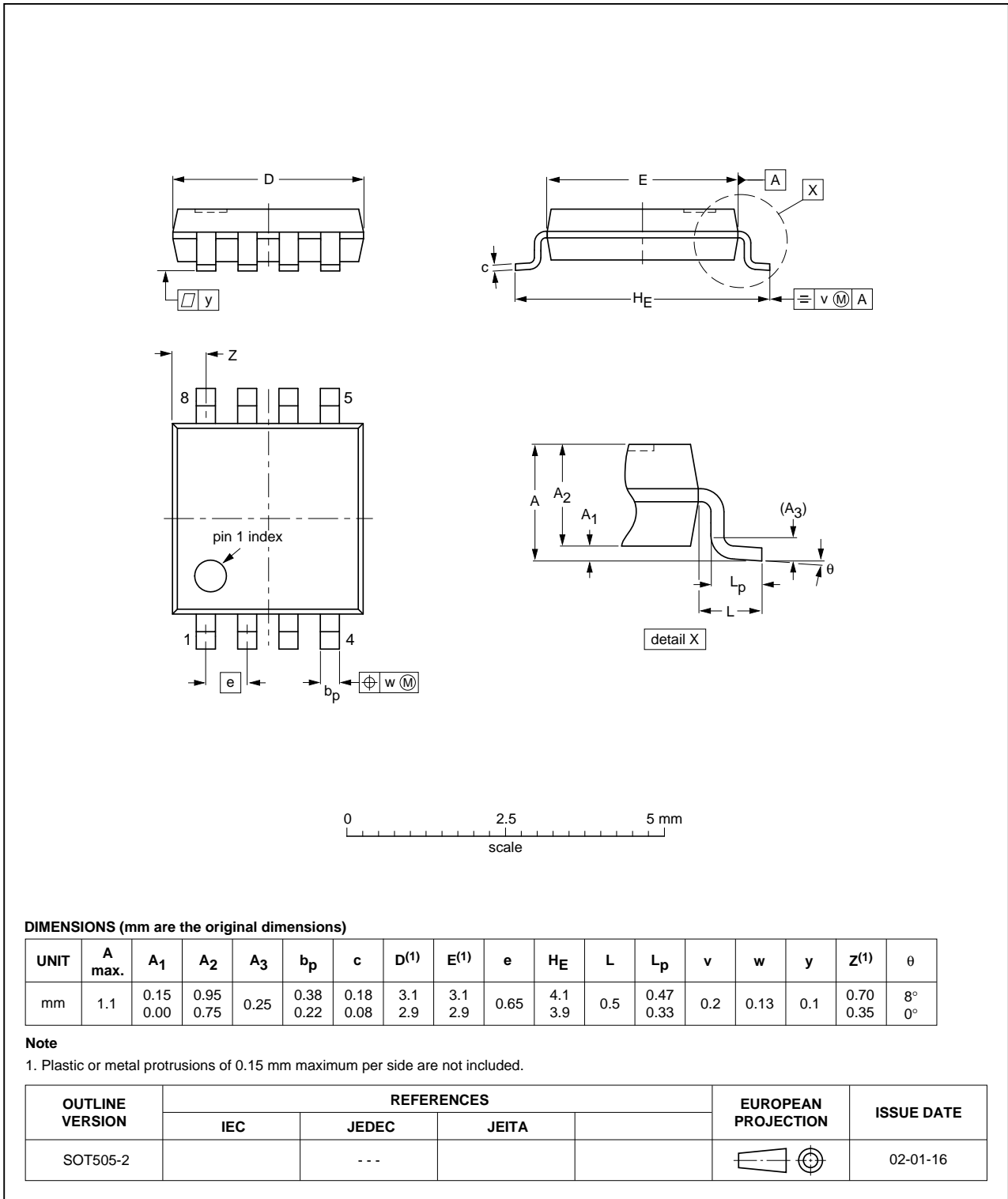


Fig 20. Package outline SOT505-2 (TSSOP8)

VSSOP8: plastic very thin shrink small outline package; 8 leads; body width 2.3 mm

SOT765-1

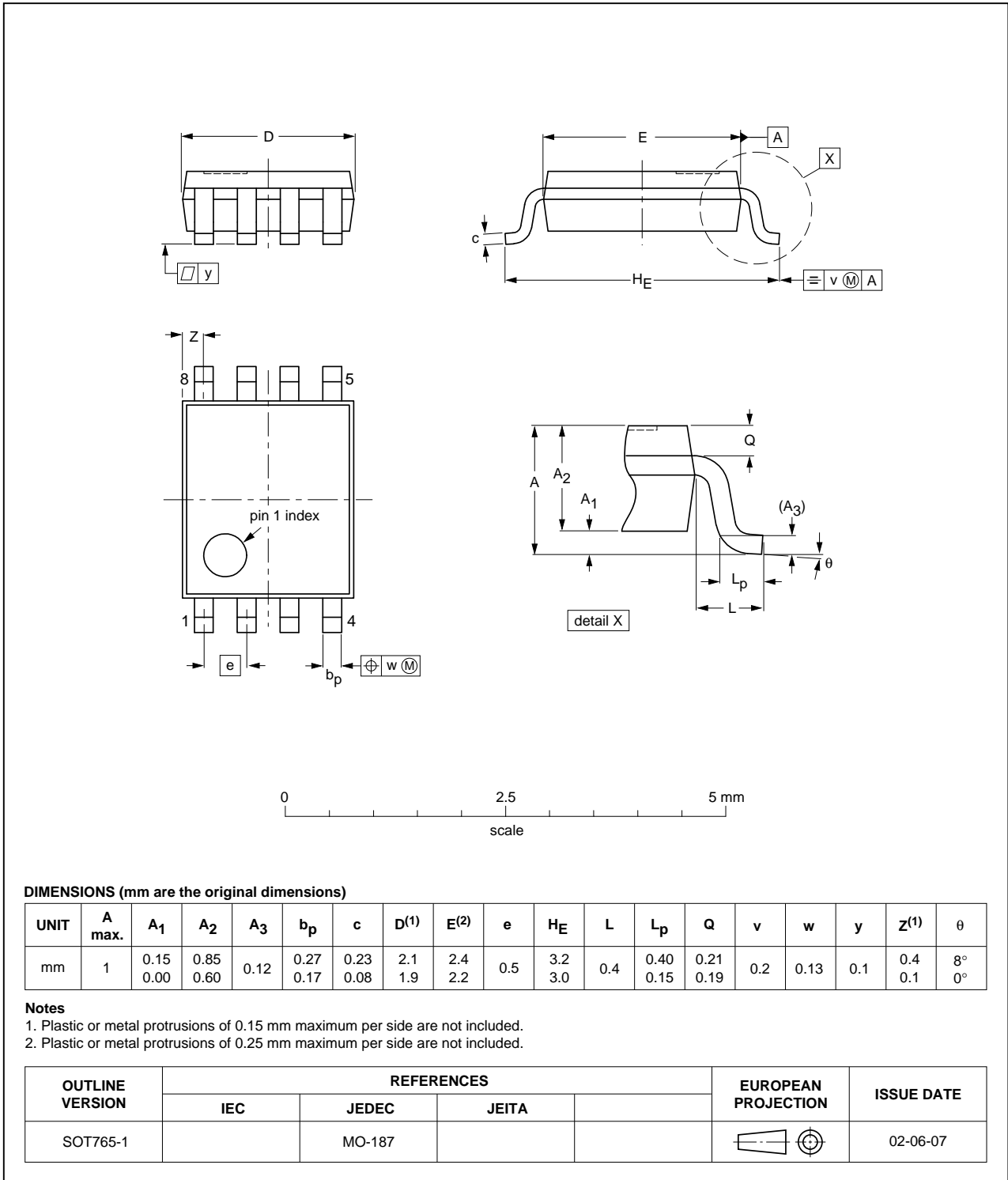


Fig 21. Package outline SOT765-1 (VSSOP8)

XSON8: plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm

SOT833-1

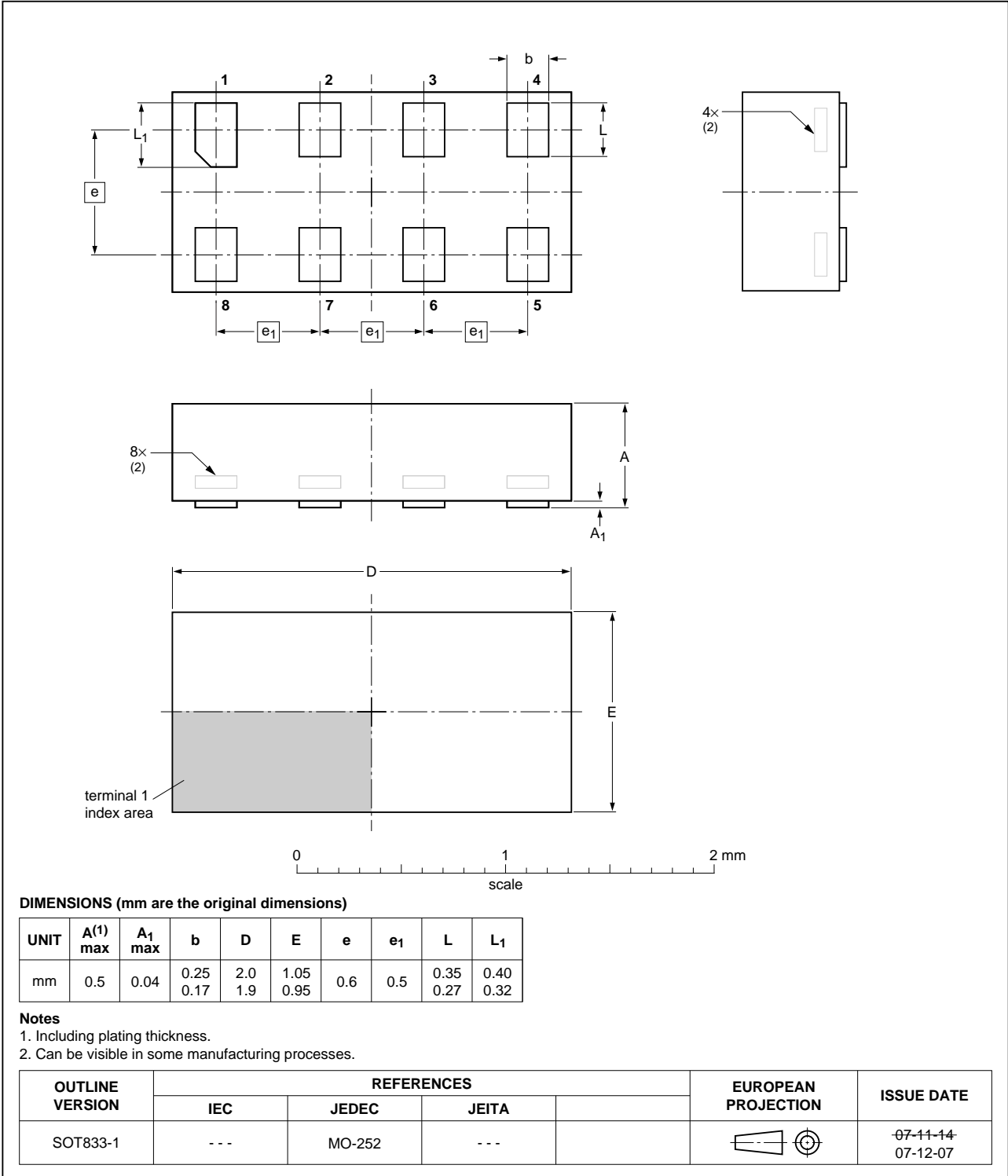


Fig 22. Package outline SOT833-1 (XSON8)

**XSON8: extremely thin small outline package; no leads;
8 terminals; body 1.35 x 1 x 0.5 mm**

SOT1089

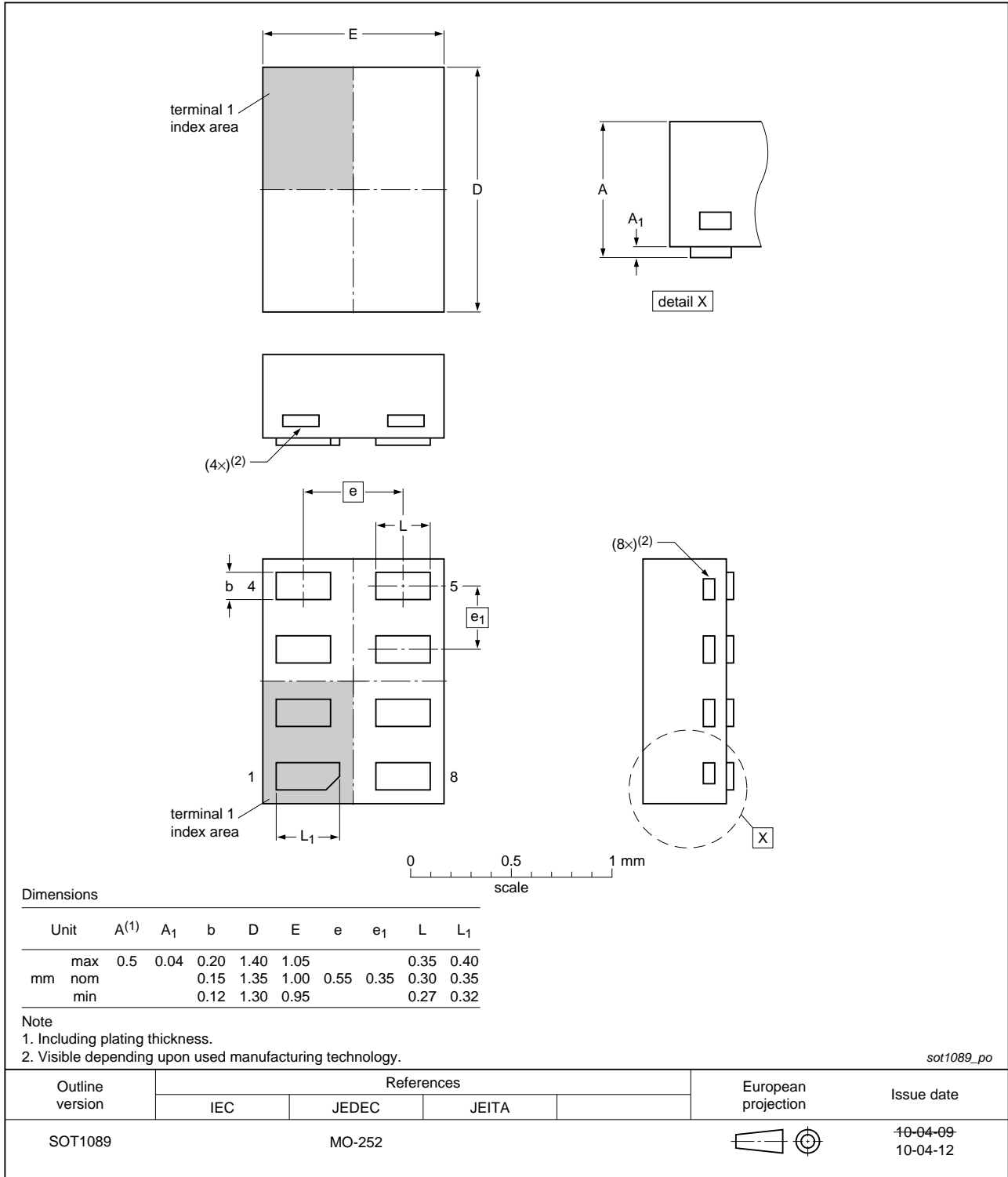


Fig 23. Package outline SOT1089 (XSON8)

XSON8U: plastic extremely thin small outline package; no leads;
8 terminals; UTLP based; body 3 x 2 x 0.5 mm

SOT996-2

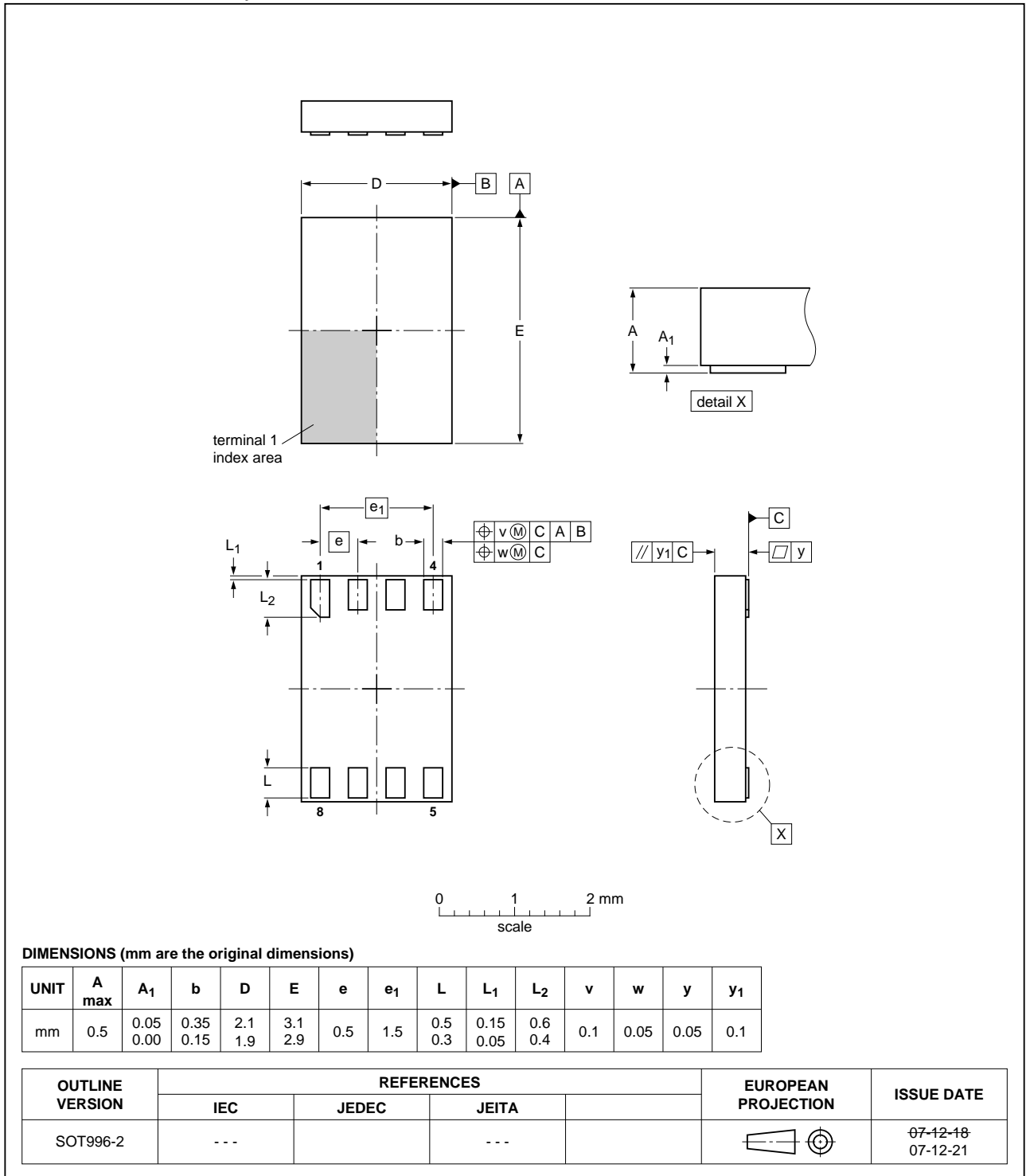


Fig 24. Package outline SOT996-2 (XSON8U)

XQFN8: plastic, extremely thin quad flat package; no leads;
8 terminals; body 1.6 x 1.6 x 0.5 mm

SOT902-2

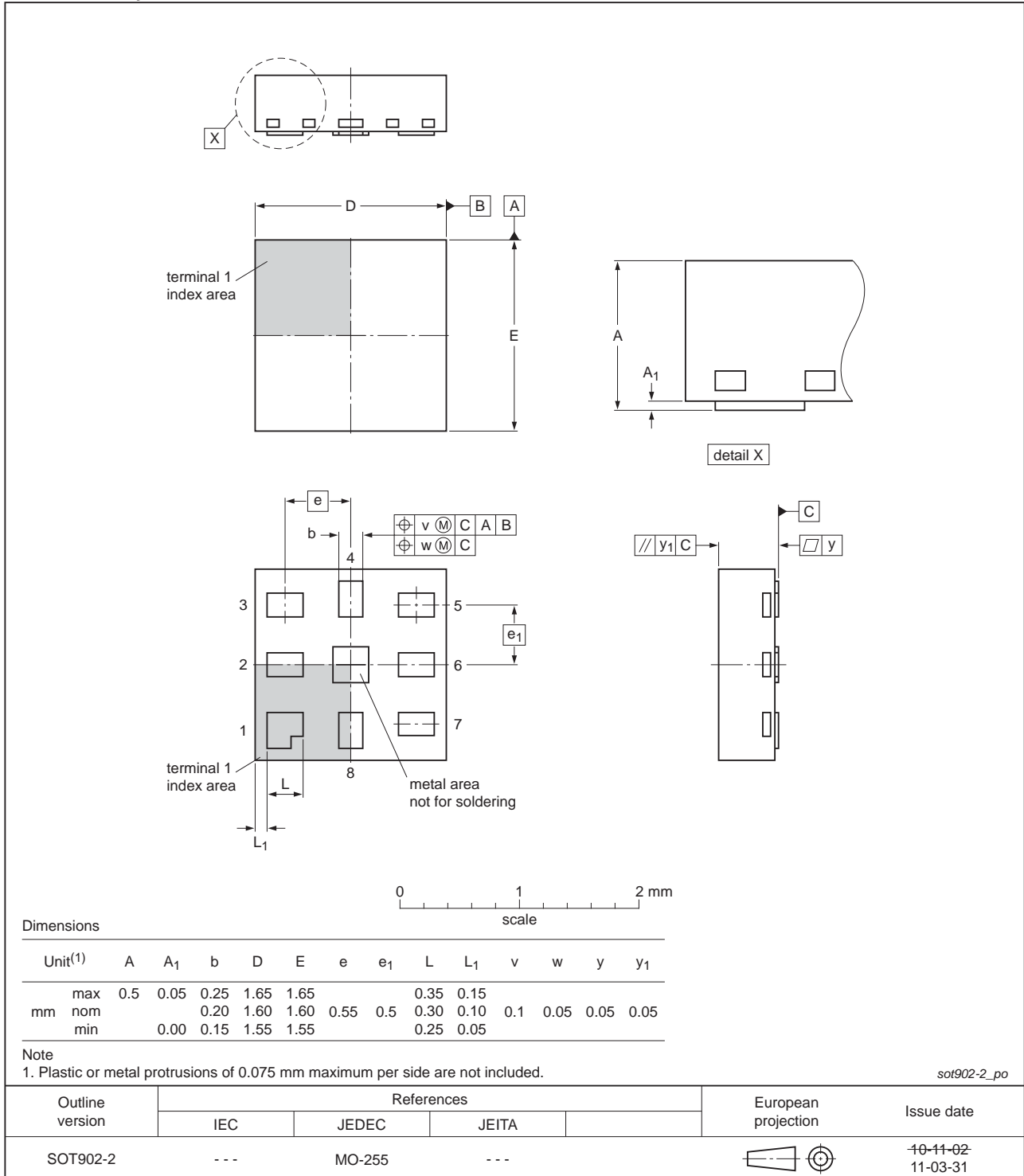


Fig 25. Package outline SOT902-2 (XQFN8)

**XSON8: extremely thin small outline package; no leads;
8 terminals; body 1.2 x 1.0 x 0.35 mm**

SOT1116

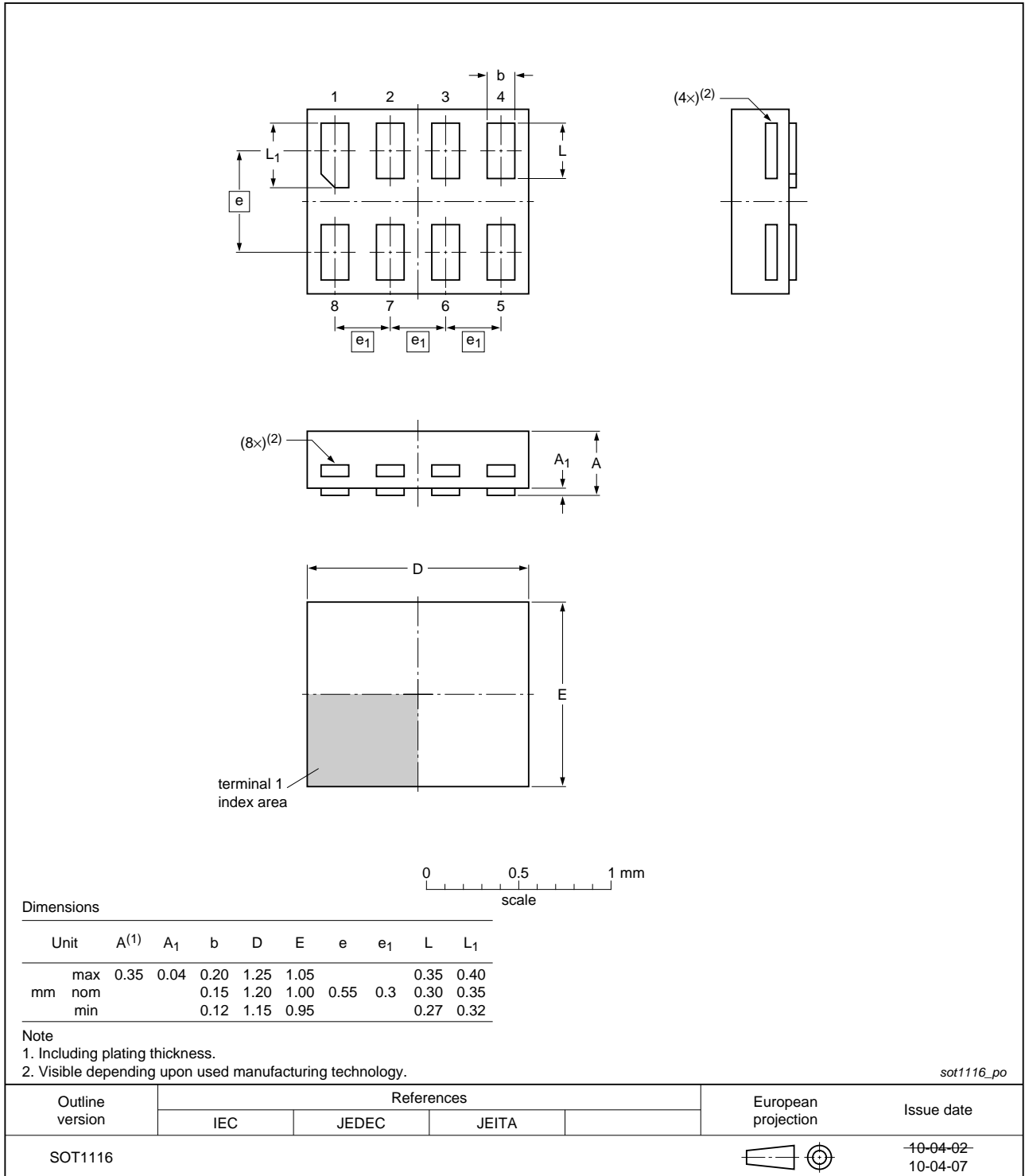


Fig 26. Package outline SOT1116 (XSON8)

**XSON8: extremely thin small outline package; no leads;
8 terminals; body 1.35 x 1.0 x 0.35 mm**

SOT1203

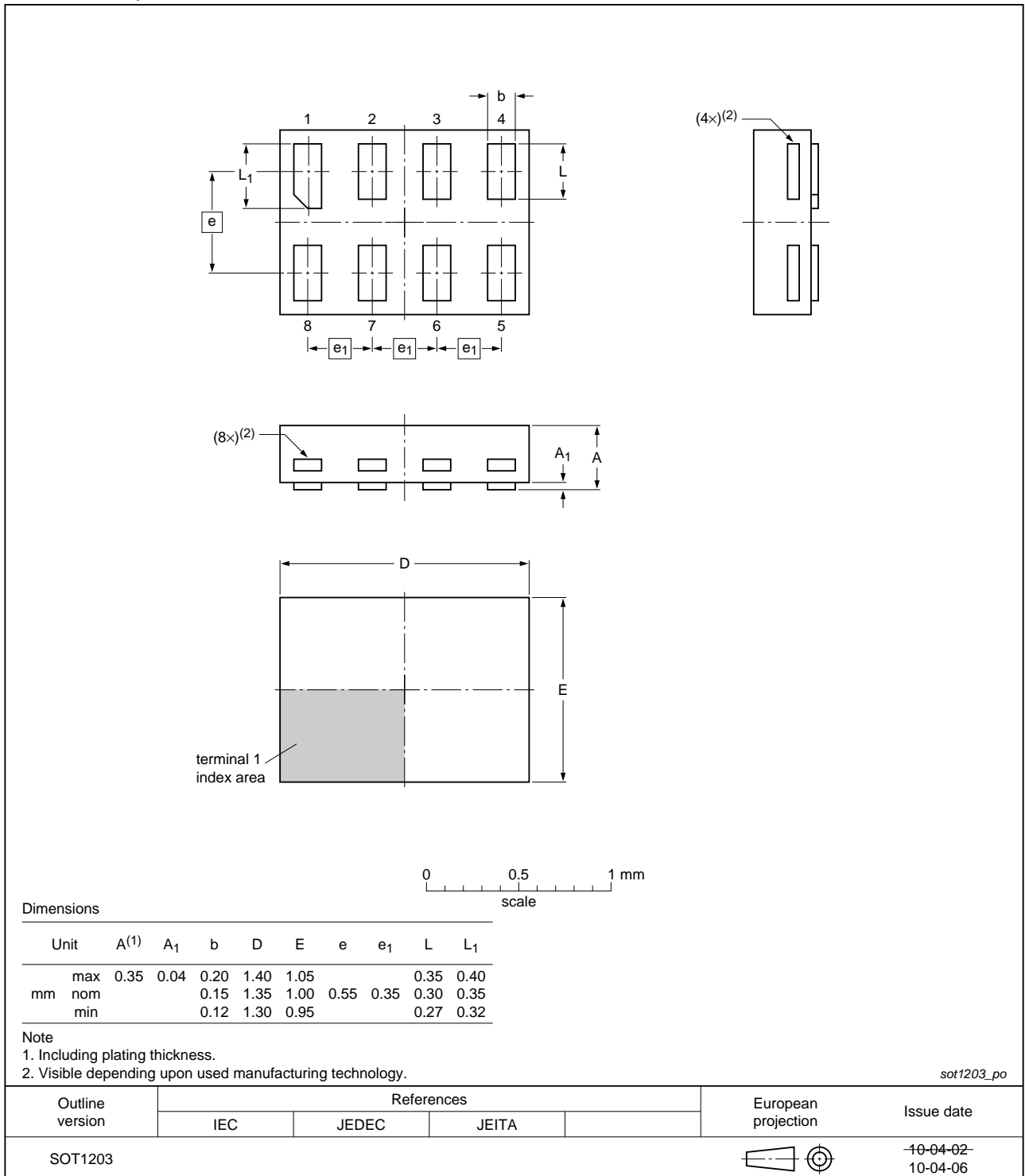


Fig 27. Package outline SOT1203 (XSON8)

14. Abbreviations

Table 12. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G123 v.1	20120123	Product data sheet	-	-

16. Legal information

16.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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